

**IN THE CLAIMS**

Please amend claims 9 through 11, and add claims 12 through 14 as follows:

1. (Previously Amended) A magnesium titanate implant, comprising:  
an implant body containing titanium or a titanium alloy; and  
a magnesium titanate oxide film formed on the surface of the said implant body in a single or mixed solution containing magnesium by low voltage dielectric breakdown anodic oxidation.

Claim 2. (Canceled)

3. (Previously Amended) The magnesium titanate implant as set forth in claim 1, wherein the magnesium titanate oxide film contains 6 to 26% of titanium, 51 to 71% of oxygen and 1.8 to 32% of magnesium, as main ingredients.

4. (Previously Amended) The magnesium titanate implant as set forth in claim 1, wherein the magnesium titanate oxide film has a bilayer structure including an upper porous layer and a lower barrier layer.

5. (Previously Amended) The magnesium titanate implant as set forth in claim 1, wherein the magnesium titanate oxide film has a thickness of 300 nm to 30  $\mu$ m.

6. (Original) The magnesium titanate implant as set forth in claim 5, wherein the magnesium titanate oxide film has a thickness of 500 nm to 10  $\mu\text{m}$ .

7. (Original) A process for preparing a magnesium titanate oxide film implant, comprising:

irradiating UV light on an implant body made of titanium or a titanium alloy in distilled water for more than 2 hours;

dipping the UV light-irradiated implant body in an electrolyte solution containing magnesium; and

coating a magnesium titanate oxide film on the dipped implant body by anodic oxidation at a voltage of 60 to 500V.

8. (Original) The process as set forth in claim 7, wherein the electrolyte solution is a single or mixed solution containing magnesium.

9. (Currently Amended) The process as set forth in claim 7 ~~or 8~~, wherein the electrolyte solution has a concentration ranging from 0.01M to 1.0M.

10. (Currently Amended) The process as set forth in claim 7 ~~or 8~~, wherein the electrolyte solution has a pH of 3.0 to 12.5.

11. (Currently Amended) The process as set forth in claim 7 ~~or~~ 8, wherein the current density for performing the anodic oxidation is within the range of 30 to 4000 mA/cm<sup>2</sup>.

12. (New) The process as set forth in claim 8, wherein the electrolyte solution has a concentration ranging from 0.01M to 1.0M.

13. (New) The process as set forth in claim 8, wherein the electrolyte solution has a pH of 3.0 to 12.5.

14. (New) The process as set forth in claim 8, wherein the current density for performing the anodic oxidation is within the range of 30 to 4000 mA/cm<sup>2</sup>.